

# TPCA8131

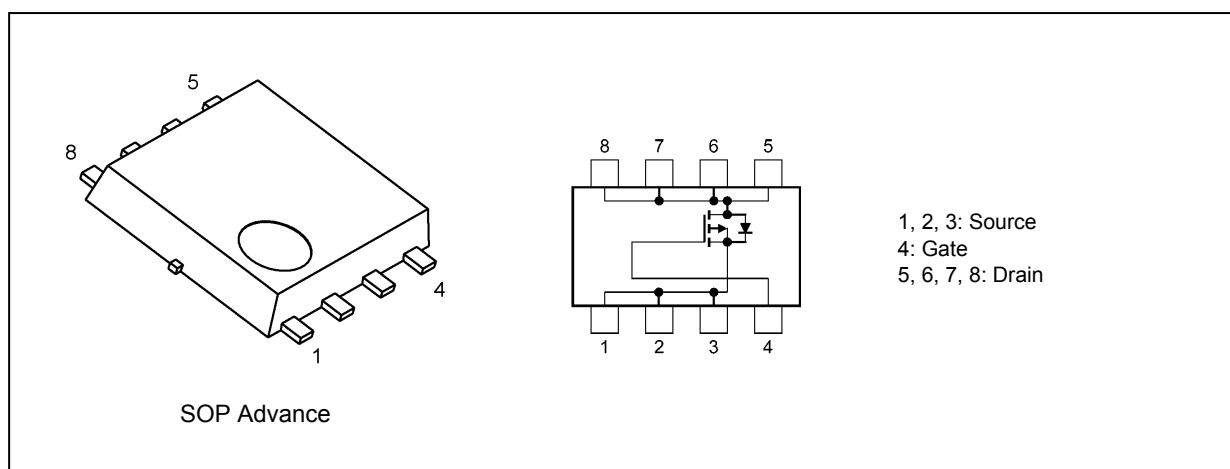
## 1. Applications

- Lithium-Ion Secondary Batteries
- Power Management Switches

## 2. Features

- (1) Small, thin package
- (2) Low drain-source on-resistance:  $R_{DS(ON)} = 12.4 \text{ m}\Omega$  (typ.) ( $V_{GS} = -10 \text{ V}$ )
- (3) Low leakage current:  $I_{DSS} = -10 \text{ }\mu\text{A}$  (max) ( $V_{DS} = -30 \text{ V}$ )
- (4) Enhancement mode:  $V_{th} = -0.8$  to  $-2.0 \text{ V}$  ( $V_{DS} = -10 \text{ V}$ ,  $I_D = -0.2 \text{ mA}$ )

## 3. Packaging and Internal Circuit



## 4. Absolute Maximum Ratings (Note) ( $T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Gate-source voltage	$V_{GSS}$	-25/+20	
Drain current (DC)	$I_D$	-13	A
Drain current (pulsed)	$I_{DP}$	-39	
Power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_D$	27	W
Power dissipation ( $t = 10 \text{ s}$ )	$P_D$	2.8	W
Power dissipation ( $t = 10 \text{ s}$ )	$P_D$	1.6	W
Single-pulse avalanche energy	$E_{AS}$	50	mJ
Avalanche current	$I_{AR}$	-13	A
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production  
2011-05

**5. Thermal Characteristics**

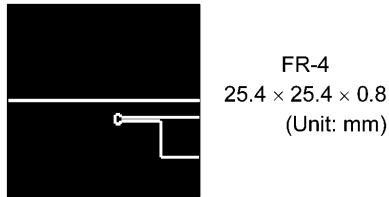
Characteristics			Symbol	Max	Unit
Channel-to-case thermal resistance	( $T_c = 25^\circ\text{C}$ )		$R_{th(ch-c)}$	4.62	$^\circ\text{C/W}$
Channel-to-ambient thermal resistance	( $t = 10\text{ s}$ )	(Note 2)	$R_{th(ch-a)}$	44.6	
Channel-to-ambient thermal resistance	( $t = 10\text{ s}$ )	(Note 3)	$R_{th(ch-a)}$	78.1	$^\circ\text{C/W}$

Note 1: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

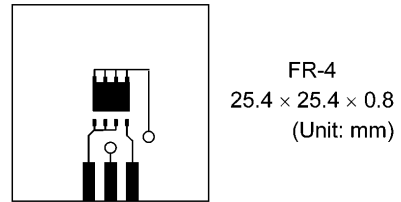
Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4:  $V_{DD} = -24\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 0.232\text{ mH}$ ,  $R_G = 25\ \Omega$ ,  $I_{AR} = -13\text{ A}$



**Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)**



**Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)**

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

**6. Electrical Characteristics**

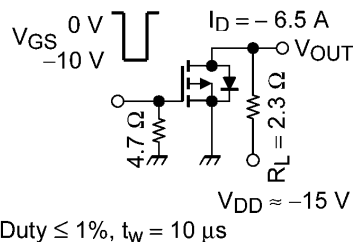
**6.1. Static Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 0.1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$	—	—	-10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -10\text{ mA}, V_{GS} = 0\text{ V}$	-30	—	—	V
Drain-source breakdown voltage (Note 5)	$V_{(BR)DSX}$	$I_D = -10\text{ mA}, V_{GS} = 10\text{ V}$	-21	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = -10\text{ V}, I_D = -0.2\text{ mA}$	-0.8	—	-2.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = -4.5\text{ V}, I_D = -6.5\text{ A}$	—	16.6	22	$\text{m}\Omega$
		$V_{GS} = -10\text{ V}, I_D = -6.5\text{ A}$	—	12.4	17	

Note 5: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

**6.2. Dynamic Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1700	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	280	—	
Output capacitance	$C_{oss}$		—	320	—	
Switching time (rise time)	$t_r$	See Figure 6.2.1.	—	6.8	—	$\text{ns}$
Switching time (turn-on time)	$t_{on}$		—	13	—	
Switching time (fall time)	$t_f$		—	52	—	
Switching time (turn-off time)	$t_{off}$		—	162	—	



**Fig. 6.2.1 Switching Time Test Circuit**

**6.3. Gate Charge Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx -24\text{ V}, V_{GS} = -10\text{ V}, I_D = -13\text{ A}$	—	40	—	$\text{nC}$
Gate-source charge 1	$Q_{gs1}$		—	4.2	—	
Gate-drain charge	$Q_{gd}$		—	10	—	

**6.4. Source-Drain Characteristics ( $T_a = 25^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 6)	$I_{DRP}$	—	—	—	-39	A
Diode forward voltage	$V_{DSF}$	$I_{DR} = -13\text{ A}, V_{GS} = 0\text{ V}$	—	—	1.2	V

Note 6: Ensure that the channel temperature does not exceed  $150^\circ\text{C}$ .

7. Marking

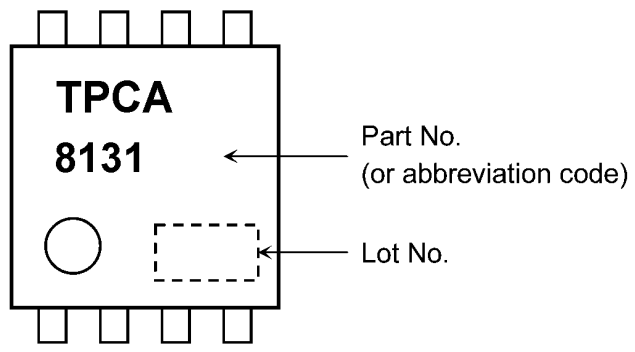
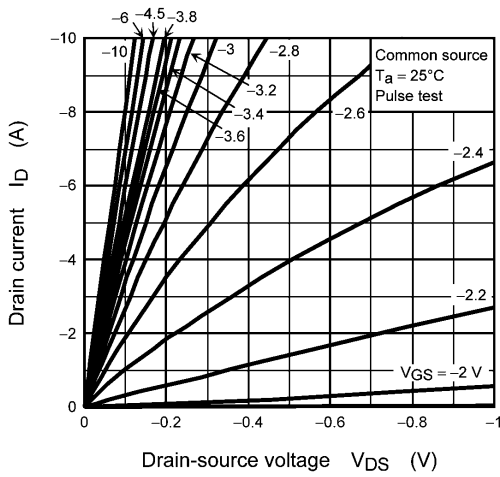
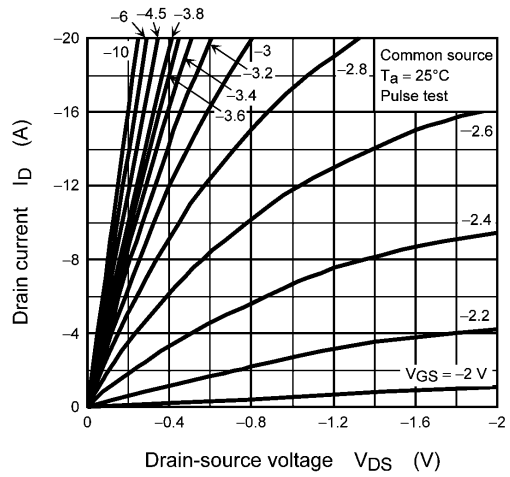


Fig. 7.1 Marking

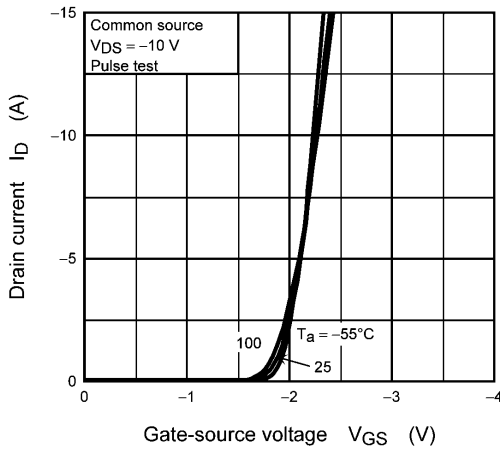
**8. Characteristics Curves (Note)**



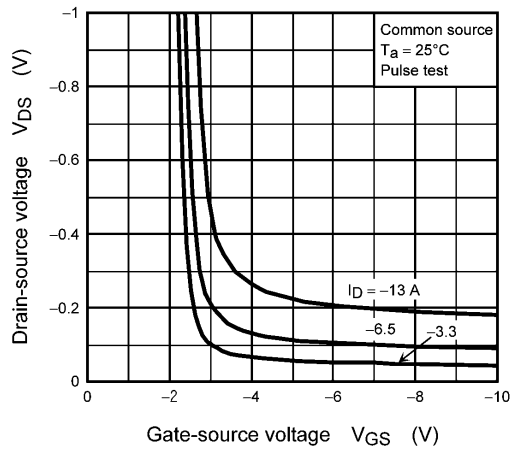
**Fig. 8.1  $I_D - V_{DS}$**



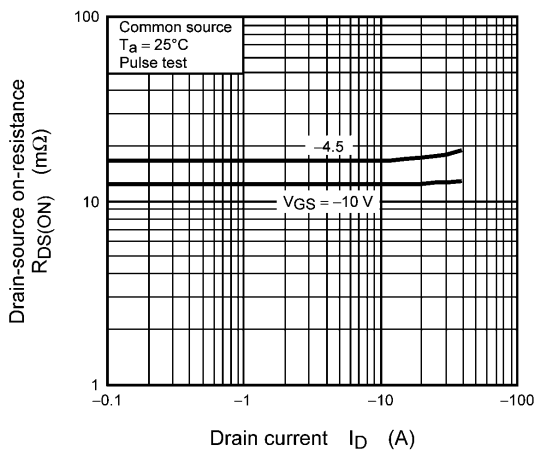
**Fig. 8.2  $I_D - V_{DS}$**



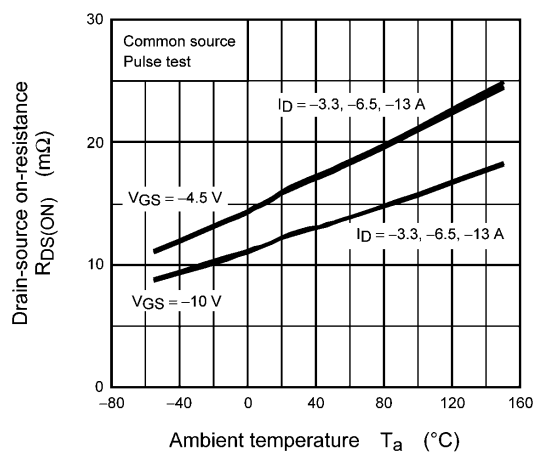
**Fig. 8.3  $I_D - V_{GS}$**



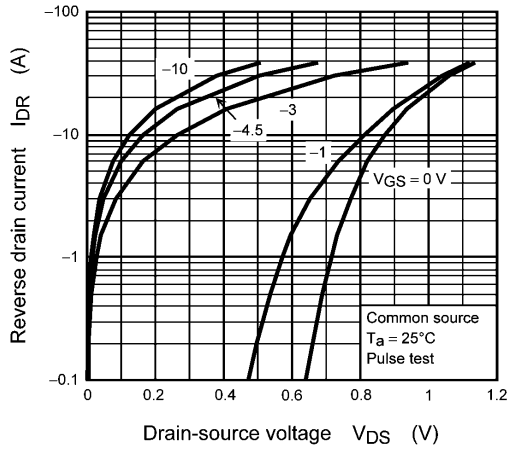
**Fig. 8.4  $V_{DS} - V_{GS}$**



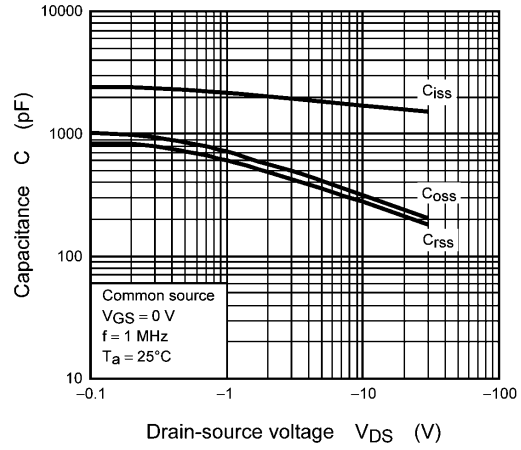
**Fig. 8.5  $R_{DS(ON)} - I_D$**



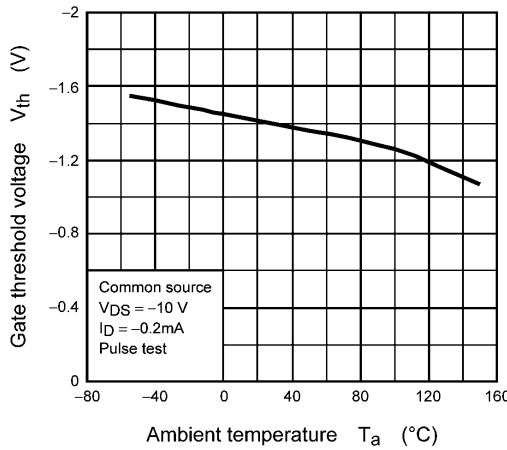
**Fig. 8.6  $R_{DS(ON)} - T_a$**



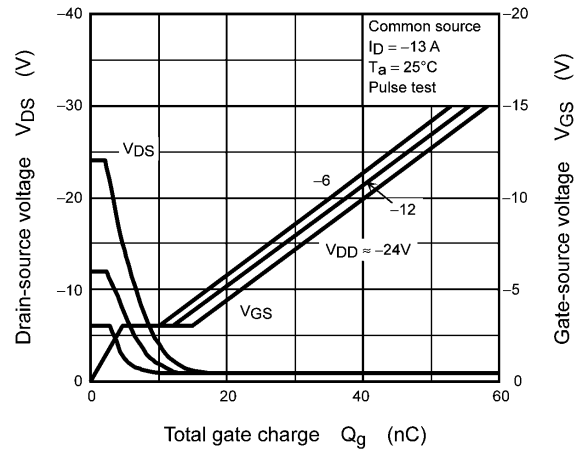
**Fig. 8.7  $I_{DR} - V_{DS}$**



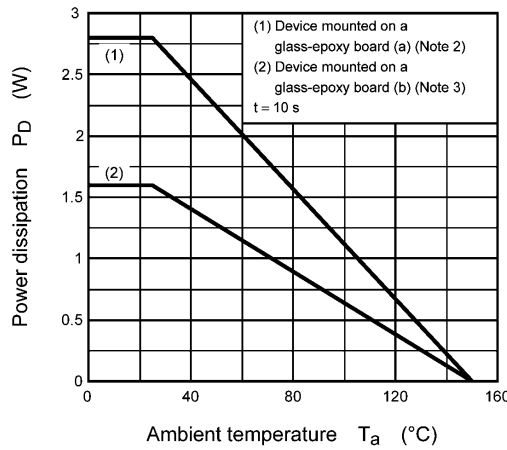
**Fig. 8.8 Capacitance -  $V_{DS}$**



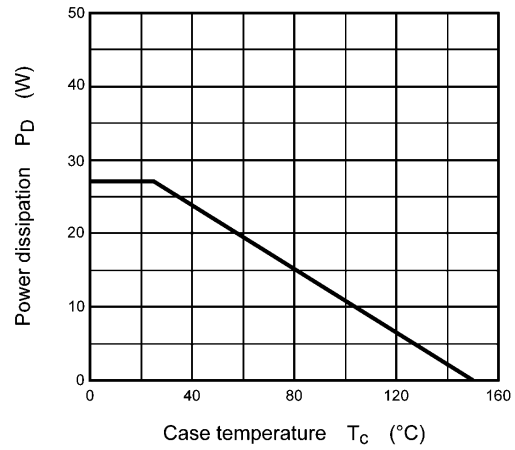
**Fig. 8.9  $V_{th} - T_a$**



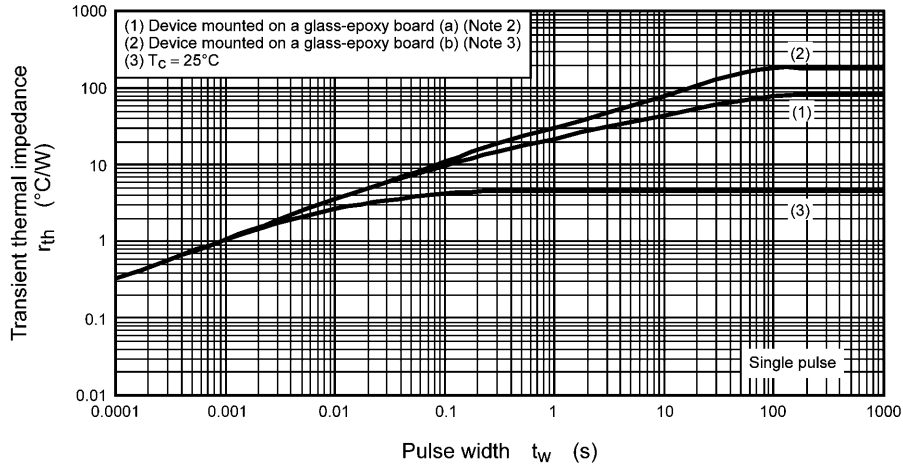
**Fig. 8.10 Dynamic Input/Output Characteristics**



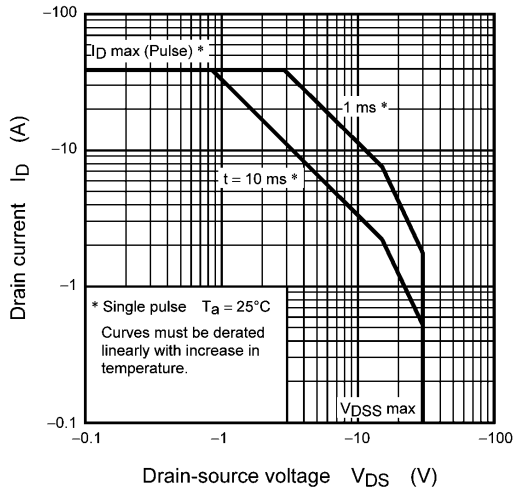
**Fig. 8.11  $P_D - T_a$  (Guaranteed Maximum)**



**Fig. 8.12  $P_D - T_c$  (Guaranteed Maximum)**



**Fig. 8.13  $r_{th} - t_w$**   
**(Guaranteed Maximum)**

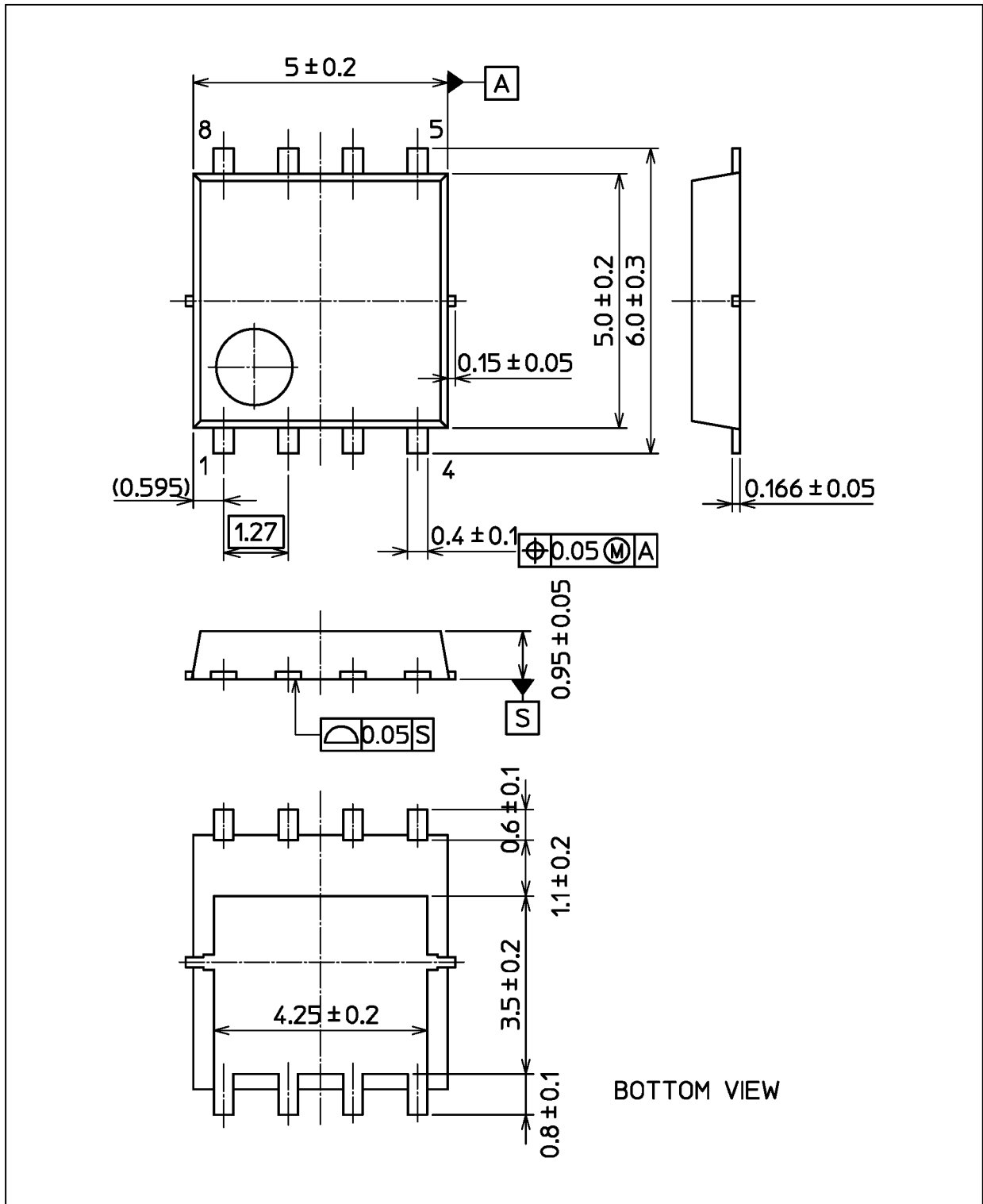


**Fig. 8.14 Safe Operating Area**  
**(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q1S
Nickname: SOP Advance

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